

Electricity

→ Electric current: rate of flow of charge

$$I = \frac{\text{charge}}{\text{time}}$$

$$I = \frac{Q}{t}$$

↳ S.I unit = ampere (A)

Charge: ^{Symbol} (C) coulomb (C) ^{unit}

time: s seconds

→ Charge, it flows because of electrons. Charge is discrete ($\times 1.6 \times 10^{-19}$)

→ Smallest possible charge: $-1.6 \times 10^{-19} \text{ C}$

If current = 3A then $\frac{3 \text{ C}}{\text{s}}$ 3 coulomb/second

$$Q = I \times t$$

$$3\text{A} \times 1 = 3 \text{ C}$$

$$3\text{A} \times 2 = 6 \text{ C}$$

⇒ Electric Field

→ it is a region around a charged object when another charged object experiences the force (attractive / repulsive).

→ the field direction is from +ve to -ve

→ the arrow in the electric field lines indicates the direction in which the positive charge will experience the force

⇒ Charge Density

Charge density = $n = \frac{\text{No. of charge carriers}}{\text{Volume}}$

drift velocity = v

$$n = \frac{N}{V}$$

$$V = l \times A$$

total no. of charges: nVl

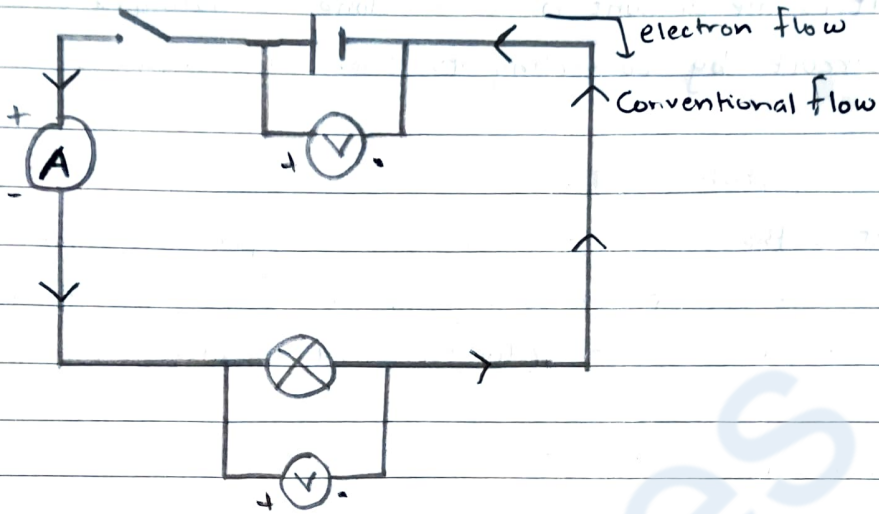
$$N = nV$$

$$Q = n \times l \times A \times q$$

$$I = \frac{Q}{t} = \frac{nAql \times l}{\frac{l}{v}}$$

$$I = nAqv$$

$$I = nAqv$$



Voltage = $\frac{\text{work done}}{\text{charge}}$

$$V = \frac{W}{Q}$$

S.I unit = $\frac{J}{C}$ or volts (V)

$W = V \times Q$, energy gained by the charge $E = V \times Q$

$$I = \frac{Q}{t}$$

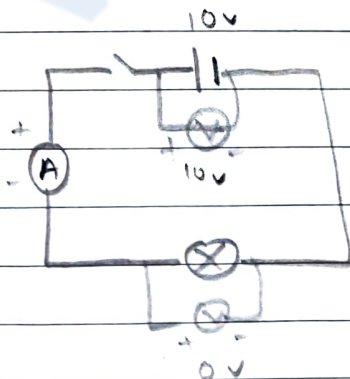
$$Q = I \times t$$

$$E = V \times I \times t$$

power = $\frac{E}{t} = \frac{V \times I \times t}{t} = \boxed{V \times I}$

S.I unit = watts (W)

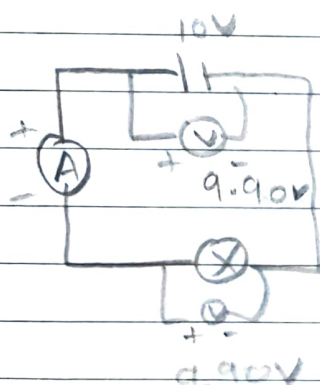
⇒ EMF



when circuit is open

$$V_1 = 10V = \text{emf (electromotive force)}$$

$$V_2 = 0V$$



when circuit is closed

$$V_1 = 9.90V \text{ (terminal potential diff)}$$

$$V_2 = 0.10V$$

$$\text{Lost Volt} = 10 - 9.90 = 0.10V$$

⇒ EMF

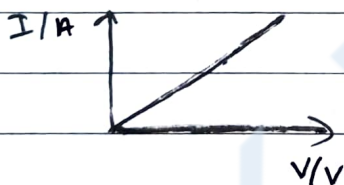
→ It is the amount of work done in moving ^{per unit} a charge within the circuit by converting its chemical energy to electrical energy.

⇒ Terminal Potential difference

→ It is the amount of work done by per unit charge in moving ~~across~~ ^{across} the appliances by converting its electrical energy into other forms of energy (light, sound, heat)

⇒ Ohm's law

→ For a conductor the current is directly proportional to the applied voltage, provided the physical condition of the given conductor remains same. (temp, C.S.A, length)



$$V \propto I$$

$$V = IR, \quad R = \text{resistance}$$

$$R = \frac{V}{I}$$

$$\text{S.I unit} = \frac{\text{Volts}}{\text{Ampere}} = \text{VA}^{-1} \text{ or ohms } \Omega$$

Symbol →  resistor

 variable resistor

⇒ Resistivity (ρ)

$$R \propto l$$

$$R \propto \frac{l}{A}$$

$$R \propto \frac{l}{A}$$

$$\rho = \frac{RA}{l}$$

$$\text{S.I unit for } \rho = \Omega \text{ m}$$

$$R = \rho \left(\frac{l}{A} \right) \text{ where } \rho \rightarrow \text{resistivity of the given conductor}$$

same resistivity

⇒ If two wires of same material have length l_1 and l_2 , cross-sectional area A_1 and A_2 respectively then →

$$R_1 = \rho \frac{l_1}{A_1}$$

$$R_2 = \rho \frac{l_2}{A_2}$$

$$\frac{R_1}{R_2} = \frac{\rho \frac{l_1}{A_1}}{\rho \frac{l_2}{A_2}}$$

$$\frac{R_1}{R_2} = \frac{l_1}{A_1} \times \frac{A_2}{l_2}$$

$$\boxed{\frac{R_1}{R_2} = \frac{l_1}{l_2} \times \frac{A_2}{A_1}}$$

$$\text{or } \boxed{\frac{R_1}{R_2} = \frac{l_1}{l_2} \times \frac{d_2^2}{d_1^2}}$$

$$\text{or } \boxed{\frac{R_1}{R_2} = \frac{l_1}{l_2} \times \frac{\gamma_2^2}{\gamma_1^2}}$$

Q.

	Wire A
length	15 cm
diameter	6 mm
Resistance	100 Ω

Wire B

length	30 cm
diameter	3 mm
Resistance	?

Find x

$$\frac{R_1}{R_2} = \frac{l_1}{l_2} \times \frac{d_2^2}{d_1^2} = \frac{100 \Omega}{x} = \frac{15}{30} \times \frac{3^2}{6^2}$$

$$\frac{100 \Omega}{x} = 0.125$$

$$\frac{100}{0.125} = x = \underline{\underline{800 \Omega}}$$

Q.

Wire A Wire B

l	2x	x
r	3y	y
	10 Ω	2

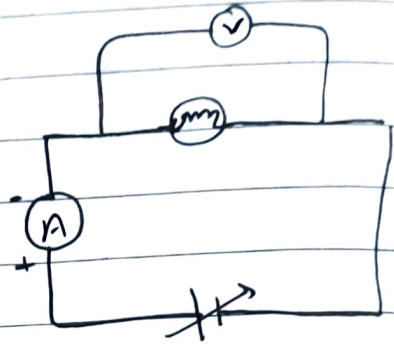
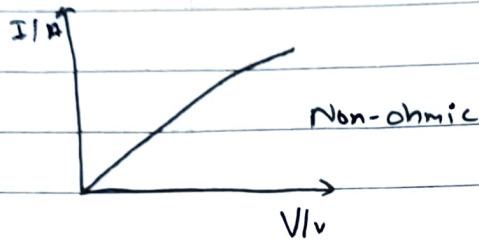
$$\frac{10}{2} = \frac{2x}{x} \times \frac{y^2}{(3y)^2}$$

$$\frac{10}{2} = \frac{2xy^2}{9xy^2}$$

$$\frac{10}{2} = \frac{2}{9}$$

$$\frac{10}{2/9} = 2 = 45 \Omega$$

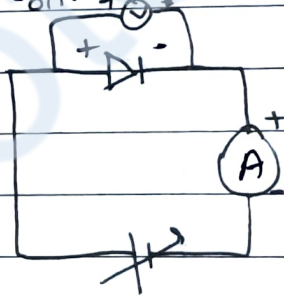
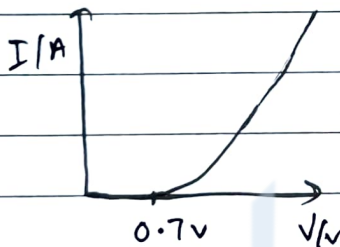
⇒ Filament lamp
I-V graph



⇒ Diodes

→ semiconductor device which allows the current to flow in one direction provided it gets the required voltage.

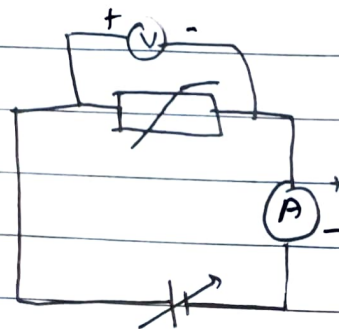
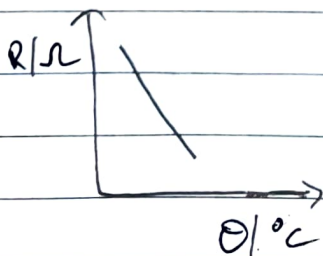
→ Silicon diode has 0.7V cut-off.



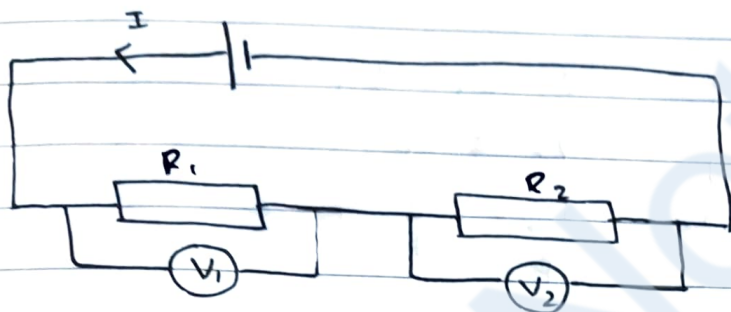
⇒ Thermistor

→ a semiconductor device whose resistance changes with the change in temp around it.

→ at low temp it offers very high resistance, but as temp increases resistance decreases.



⇒ Resistors connected in series



Note:

- The effective resistance > the individual resistance
- The voltage in the series circuit gets divided. $\uparrow V \uparrow R$
-

Total supplied voltage = $V = V_1 + V_2$

current flowing through circuit = I

$$V_1 = IR_1$$

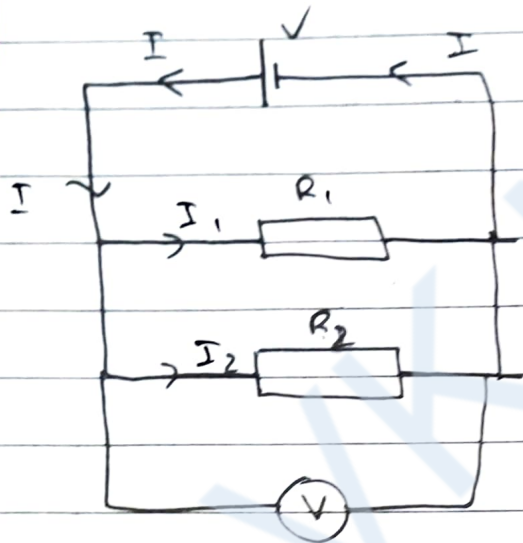
$$V_2 = IR_2$$

$$IR_s = IR_1 + IR_2$$

$$R_s = R_1 + R_2$$

R_s = effective resistance in series.

⇒ Resistors connected in parallel

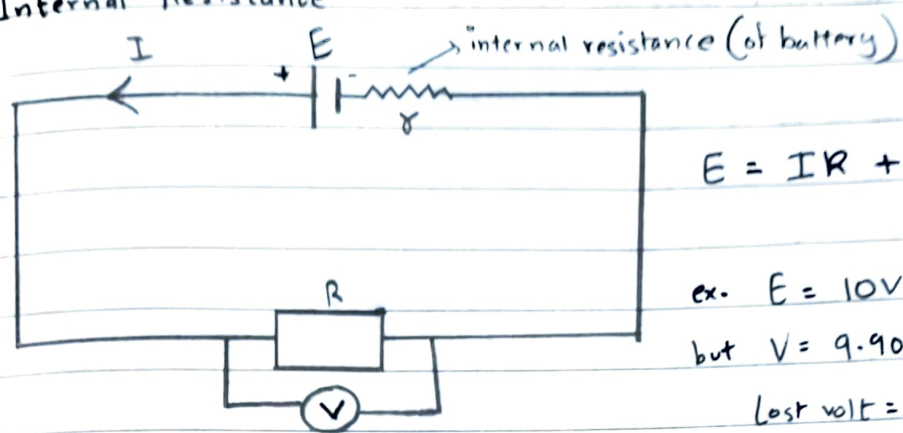


$$I = I_1 + I_2$$

$$V = I R_p$$

$$\frac{1}{R_p} = \frac{1}{R_1} + \frac{1}{R_2}$$

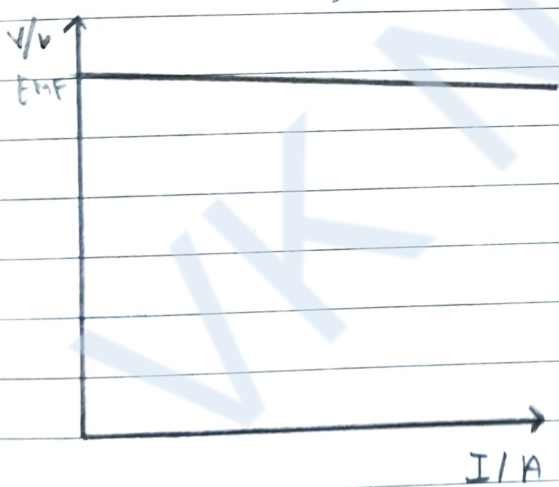
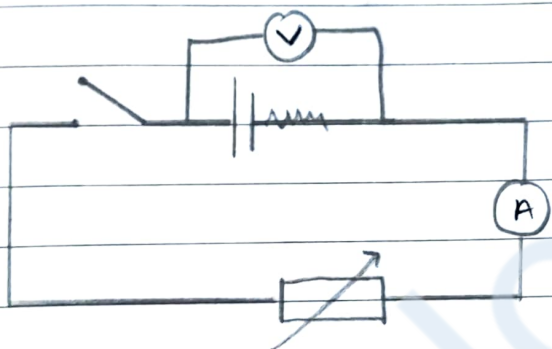
⇒ Internal Resistance



$$E = IR + Ir$$

ex. $E = 10V$
 but $V = 9.90V$

lost volt = $0.10V$
 lost volt is because of internal resistance



→ Gradient of this graph = internal resistance

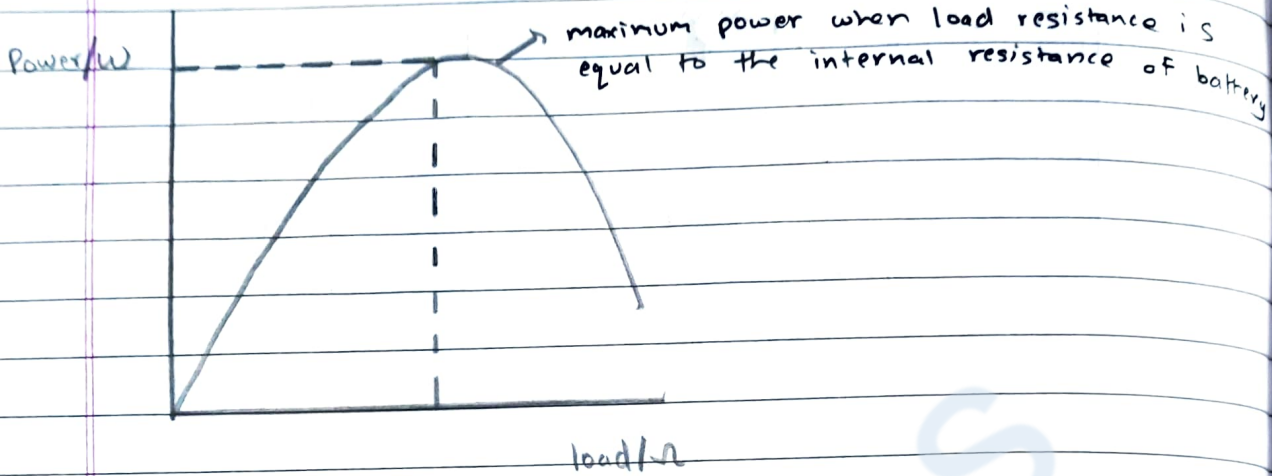
$$EMF = V + Ir$$

$$E = V + Ir$$

comparing with $y = mx + c$

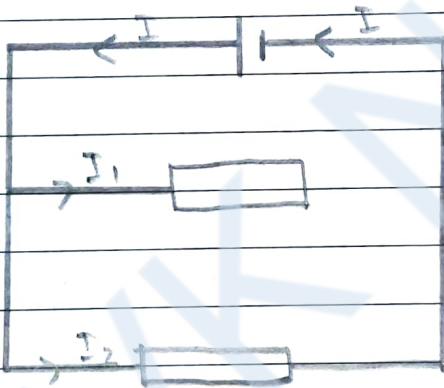
$$\begin{matrix} V = -Ir + E \\ \downarrow \quad \downarrow \quad \downarrow \\ y \quad m \quad c \end{matrix}$$

⇒ Power dissipated (graph)



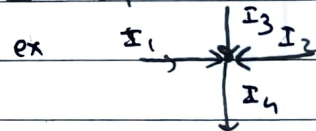
⇒ Kirchhoff's law

Ist law : conservation of charges



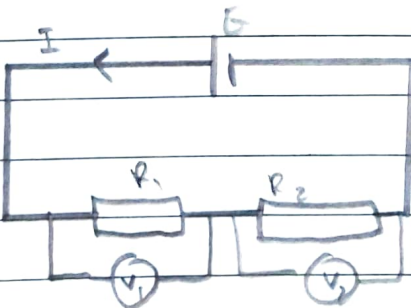
sum of current entering the junction is always equal to the sum of current leaving the junction.

$$I = I_1 + I_2$$



$$I_1 + I_2 + I_3 + I_4$$

IInd law : conservation of energy



sum of the EMF in the circuit is equal to the sum of the potential difference across the components in the circuit.

$$E = V_1 + V_2$$